NSN 5961-00-469-5784

Transistor - Page 1 of 1



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Inclosure Material:	Incl	osure	Mater	ial:
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Metal

Overall Length:

0.250 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.359 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

1.00 amperes source cutoff current and 0.05 microamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

800.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0